



RS1A/B - RS1M/B

1.0A SURFACE MOUNT FAST RECOVERY RECTIFIER

Features

- Glass Passivated Die Construction
- Fast Recovery Time For High Efficiency
- Surge Overload Rating to 30A Peak
- Ideally Suited for Automated Assembly
- Lead Free Finish/RoHS Compliant (Note 1)
- **Green Molding Compound (No Halogen and Antimony)** (Note 2)

Mechanical Data

- Case: SMA/SMB
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Lead Free Plating (Matte Tin Finish). Solderable per MIL-STD-202, Method 208 (3)
- Polarity: Cathode Band or Cathode Notch
- Weight: SMA 0.064 grams (approximate) SMB - 0.093 grams (approximate)





Bottom View

Ordering Information (Note 3)

•			
	Part Number	Case	Packaging
	RS1x-13-F	SMA	5000/Tape & Reel
	RS1xB-13-F	SMB	3000/Tape & Reel

^{*} x = Device type, e.g. RS1D-13-F (SMA package); RS1JB-13-F (SMB package).

- 1. EU Directive 2002/95/EC (RoHS). All applicable RoHS exemptions applied, see EU Directive 2002/95/EC Annex Notes. 2. Product manufactured with Data Code 0924 (week 24, 2009) and newer are built with Green Molding Compound.
- 3. For packaging details, go to our website at http://www.diodes.com.

Marking Information



RS1x = Product Type Marking Code, ex: RS1G (SMA package) RS1xB = Product Type Marking Code, ex: RS1GB (SMB package) II = Manufacturer's Code Marking YWW = Date Code Marking Y = Last Digit of Year (ex: 6 for 2006) WW = Week code (01 to 53)



Maximum Ratings @T_A = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitance load, derate current by 20%.

Characteristic	Symbol	RS1 A/AB	RS1 B/BB	RS1 D/DB	RS1 G/GB	RS1 J/JB	RS1 K/KB	RS1 M/MB	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage (Note 4)	V _{RRM} V _{RWM} V _R	50	100	200	400	600	800	1000	٧
RMS Reverse Voltage	V _{R(RMS)}	35	70	140	280	420	560	700	V
Average Rectified Output Current @ T _T = 120°C	Io				1.0				Α
Non-Repetitive Peak Forward Surge Current, 8.3ms Single Half Sine-Wave Superimposed on Rated Load	I _{FSM}				30				Α

Thermal Characteristics

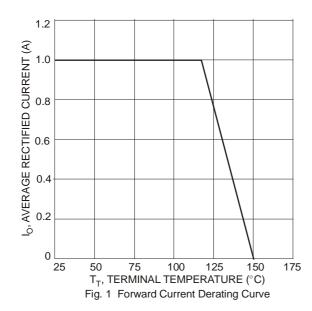
Characteristic	Symbol	Value	Unit
Typical Thermal Resistance, Junction to Terminal (Note 5)	$R_{ hetaJT}$	20	°C/W
Operating and Storage Temperature Range	T_{J}, T_{STG}	-65 to +150	°C

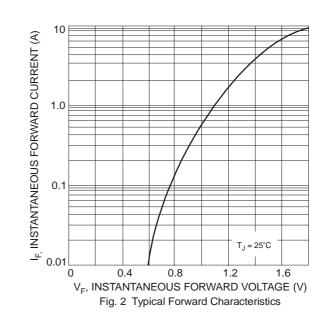
Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic		Symbol	RS1 A/AB	RS1 B/BB	RS1 D/DB	RS1 G/GB	RS1 J/JB	RS1 K/KB	RS1 M/MB	Unit
Forward Voltage Drop	@ I _F = 1.0A	V_{FM}				1.3				V
Peak Reverse Current	@ T _A = 25°C					5.0				uА
at Rated DC Blocking Voltage (Note 4)	@ T _A = 125°C	25°C IRM		200					μΑ	
Reverse Recovery Time (Note 6)	•	t _{rr}		1:	50	•	250	5	00	ns
Typical Total Capacitance (Note 7)		C _T				15				pF

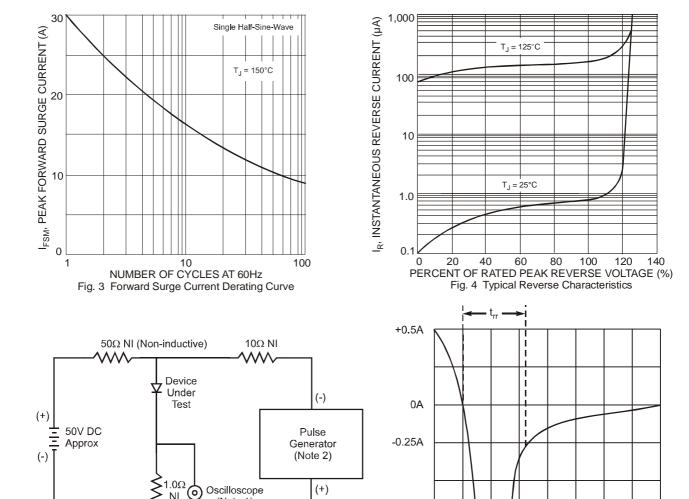
Notes:

- 4. Short duration pulse test used to minimize self-heating effect.
- 5. Valid provided that terminals are kept at ambient temperature.
- 6. Reverse recovery test conditions: $I_F = 0.5A$, $I_R = 1.0A$, $I_{rr} = 0.25A$. See figure 5.
- 7. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.









1. Rise Time = 7.0ns max. Input Impedance = $1.0M\Omega$, 22pF.

(Note 1)

2. Rise Time = 10ns max. Input Impedance = 50Ω .

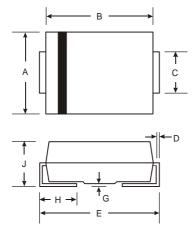
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Set time base for 50/100 ns/cm

Fig. 5 Reverse Recovery Time Characteristic and Test Circuit

-1.0A

Package Outline Dimensions

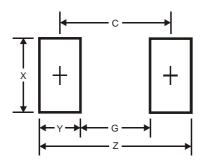


	SMA					
Dim	Dim Min Max					
Α	2.29	2.92				
В	4.00	4.60				
С	1.27	1.63				
D	0.15	0.31				
Е	4.80	5.59				
G	0.05	0.20				
Н	0.76	1.52				
J	2.01	2.30				
All Dimensions in mm						

Dim Min Max A 3.30 3.94 B 4.06 4.57 C 1.96 2.21 D 0.15 0.31 E 5.00 5.59 G 0.05 0.20 H 0.76 1.52 J 2.00 2.50 All Dimensions in mm	SMB							
B 4.06 4.57 C 1.96 2.21 D 0.15 0.31 E 5.00 5.59 G 0.05 0.20 H 0.76 1.52 J 2.00 2.50	Dim	Dim Min Max						
C 1.96 2.21 D 0.15 0.31 E 5.00 5.59 G 0.05 0.20 H 0.76 1.52 J 2.00 2.50	A	3.30	3.94					
D 0.15 0.31 E 5.00 5.59 G 0.05 0.20 H 0.76 1.52 J 2.00 2.50	В	4.06	4.57					
E 5.00 5.59 G 0.05 0.20 H 0.76 1.52 J 2.00 2.50	C 1.96 2.21							
G 0.05 0.20 H 0.76 1.52 J 2.00 2.50	D	0.15	0.31					
H 0.76 1.52 J 2.00 2.50	Е	5.00	5.59					
J 2.00 2.50	G 0.05 0.20							
	H 0.76 1.52							
All Dimensions in mm	J 2.00 2.50							



Suggested Pad Layout



SMA Dimensions	Value (in mm)
Z	6.5
G	1.5
Х	1.7
Y	2.5
С	4.0

SMB Dimensions	Value (in mm)
Z	6.7
G	1.8
X	2.3
Y	2.5
С	4.3

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